

Electronic Supplementary Information

Poling Effects on the Structural, Electrical and Photoluminescence

Properties in Sm Doped BCST Piezoelectric Ceramics

Wei Li, ^{*a} Zhe Wang, ^a Jigong Hao, ^a Peng Fu, ^a Juan Du, ^a Ruiqing Chu^b and Zhijun Xu^{*b}

^a College of Materials Science and Engineering, Liaocheng University, Liaocheng 252059, China;

^b School of Environmental and Materials Engineering, Yantai University, Yantai 264005, China.

Corresponding Authors.

*E-mail: liwei_727@163.com

**E-mail: zhjxu@sohu.com

Results and discussion section

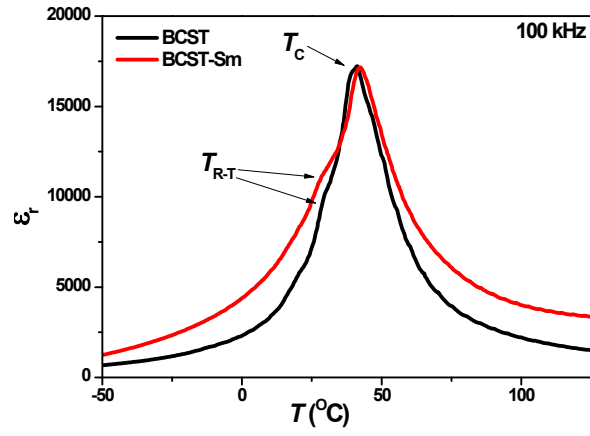


Fig. S1 The temperature dependence of dielectric constant ϵ_r and dielectric loss $\tan\delta$ of the BCST and BCST-Sm ceramics measured at 100 kHz.

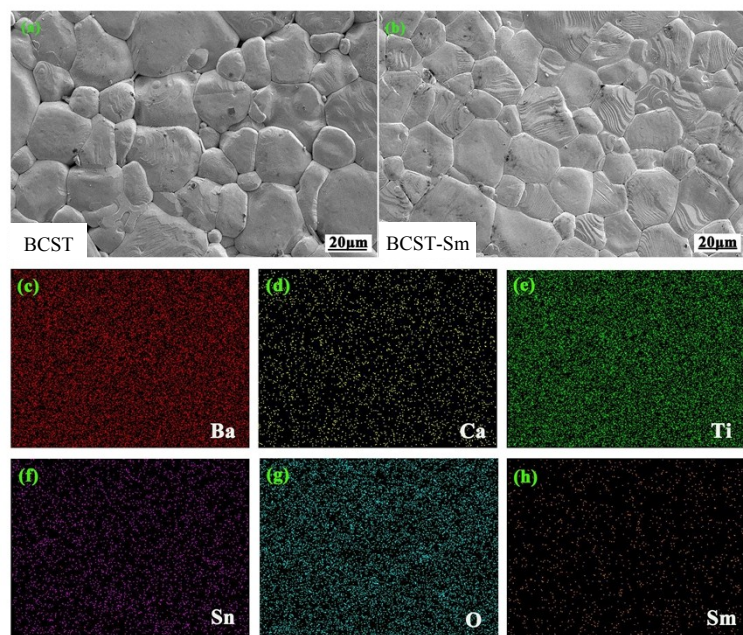


Fig. S2 The FE-SEM images of the (a) BCST, (b) BCST-Sm ceramics and (c - h) the element mappings of the BCST-Sm ceramics.

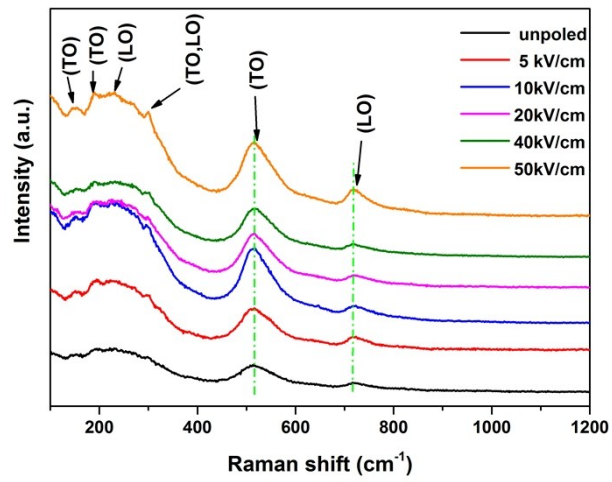


Fig. S3 Raman spectroscopy of the unpoled and poled BCST-Sm ceramics under different electric fields (5, 10, 20, 40 and 50 kV/cm).